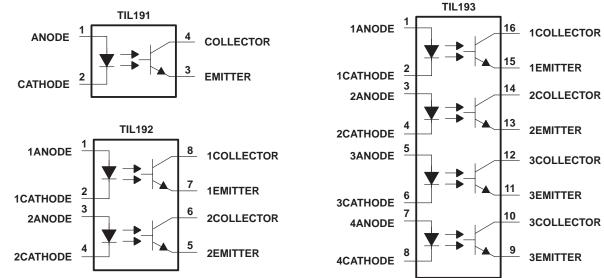
- Gallium-Arsenide-Diode Infrared Source
- Source Is Optically Coupled to Silicon npn Phototransistor
- Choice of One, Two, or Four Channels
- Choice of Three Current-Transfer Ratios

### description

These optocouplers consist of one gallium-arsenide light-emitting diode and one silicon npn phototransistor per channel. The TIL191 has a single channel in a 4-pin package, the TIL192 has two channels in an 8-package, and the TIL193 has four channels in a 16-pin package. The standard devices, TIL191, TIL192, and TIL193, are tested for a current-transfer ratio of 20% minimum. Devices selected for a current-transfer ratio of 50% and 100% minimum are designated with the suffix A and B respectively.

### schematic diagrams



### absolute maximum ratings at 25°C free-air (unless otherwise noted)<sup>†</sup>

Input-to-output voltage (see Note 1)	
Emitter-collector voltage	
Input diode reverse voltage	
Input diode continuous forward current at (or below) 25°C free-air temperature (see Note 3)	
Continuous total power dissipation at (or below) 25°C free-air temperature:	
Phototransistor (see Note 4)	150 mW
Input diode plus phototransistor per channel (see Note 5)	200 mW
Storage temperature range, T <sub>stg</sub>	-55°C to 125°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. This rating applies for sine-wave operation at 50 Hz or 60 Hz. This capability is verified by testing in accordance with UL requirements.

- 2. This value applies when the base-emitter diode is open circuited.
- 3. Derate linearly to 100°C free-air temperature at the rate of 0.67 mA/°C.
- 4. Derate linearly to  $100^{\circ}$ C free-air temperature at the rate of 2 mW/°C.
- 5. Derate linearly to 100°C free-air temperature at the rate of 2.67 mW/°C.



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- High-Voltage Electrical Isolation 3.535 kV Peak (2.5 kV rms)
- Plastic Dual-In-Line Packages
- UL Listed File #E65085

## TIL191, TIL192, TIL193, TIL191A, TIL192A, TIL193A TIL191B, TIL192B, TIL193B OPTOCOUPLERS

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### electrical characteristics 25°C free-air temperature range (unless otherwise noted)

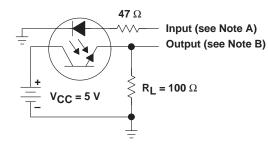
PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
V(BR)CEO	Collector-emitter breakdown voltage		I <sub>C</sub> = 0.5 mA,	IF = 0	35			V
V(BR)ECO	Emitter-collector breakdown voltage		I <sub>C</sub> = 100 μA,	IF = 0	7			V
IR	Input diode static reverse current		V <sub>R</sub> = 5 V				10	μA
IC(off))	Off-state collector current		V <sub>CE</sub> = 24 V,	IF = 0			100	nA
		TIL191, TIL192, TIL193			20%			
CTR	Current transfer ratio	TIL191A, TIL192A, TIL193A	I <sub>F</sub> = 5 mA,	V <sub>CE</sub> = 5 V	50%			
		TIL191B, TIL192B, TIL193B	1		100%			
VF	Input diode static forward voltage		I <sub>F</sub> = 20 mA				1.4	V
VCE(sat)	Collector-emitter saturation voltage		I <sub>F</sub> = 5 mA,	I <sub>C</sub> = 1 mA			0.4	V
C <sub>io</sub>	Input-to-output capacitance		V <sub>in–out</sub> = 0 mA, See Note 6	f = 1 MHz,		1		pF
rio	Input-to-output internal resistance		$V_{in-out} = \pm 1 \text{ mA},$	See Note 6		10 <sup>11</sup>		Ω

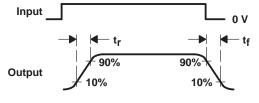
NOTE 6: These parameters are measured between all input diode leads shorted together and all phototransistor leads shorted together.

### switching characteristics at 25°C free-air temperature

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
tr	Rise time	$V_{CC} = 5 V, I_{C(O)}$	I <sub>C(on)</sub> = 2 mA,		6		
t <sub>f</sub>	Fall time	$R_L = 100 \Omega$ , S	See Figure 1		6		μs

### PARAMETER MEASUREMENT INFORMATION





NOTE C. Adjust amplitude of input pulse for  $I_{C(on)} = 2 \text{ mA}$ 

#### **TEST CIRCUIT**

VOLTAGE WAVEFORMS

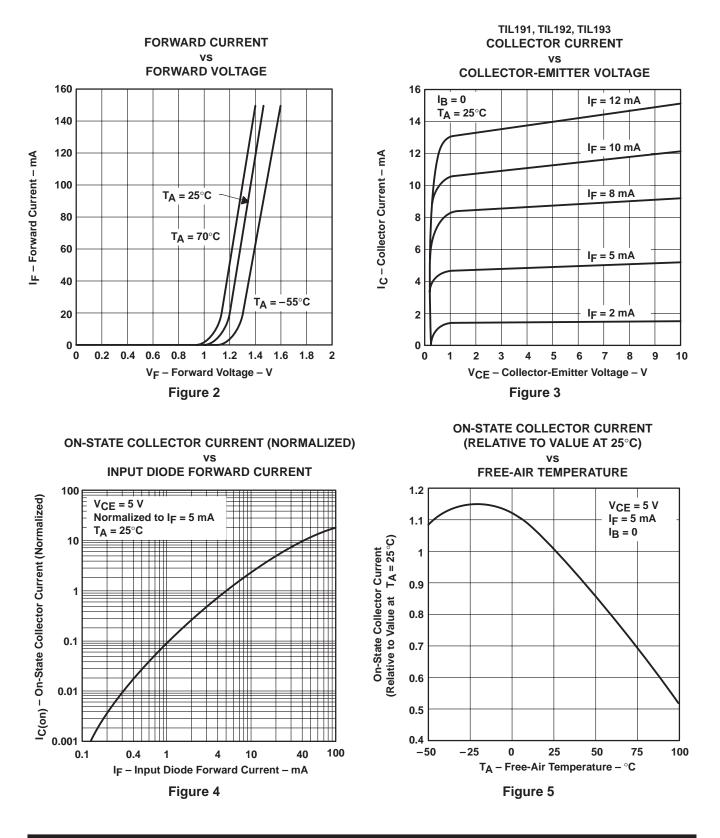
- NOTES: A. The input waveform is supplied by a generator with the following characteristics:  $Z_{OUT}$  = 50  $\Omega$ , t<sub>r</sub>  $\leq$  15 ns, duty cycle  $\approx$  1%, t<sub>w</sub> = 100  $\mu$ s.
  - B. The output waveform is monitored on a oscilloscope with the following characteristic:  $t_r \le 12$  ns,  $R_{in} \ge 1$  M $\Omega$ ,  $C_{in} \le 20$  pF.

### **Figure 1. Switching Times**

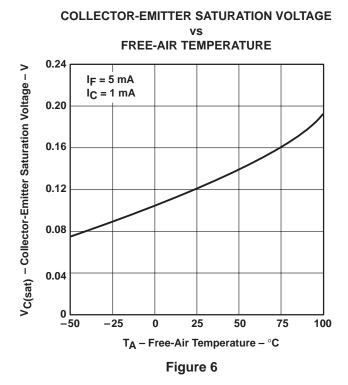


TIL191, TIL192, TIL193, TIL191A, TIL192A, TIL193A TIL191B, TIL192B, TIL193B OPTOCOUPLERS SOES026B – APRIL 1989 – REVISED APRIL 1998

### **TYPICAL CHARACTERISTICS**

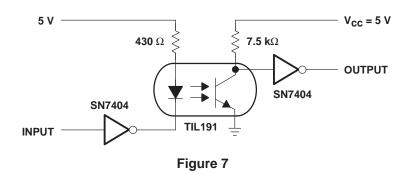






# TYPICAL CHARACTERISTICS

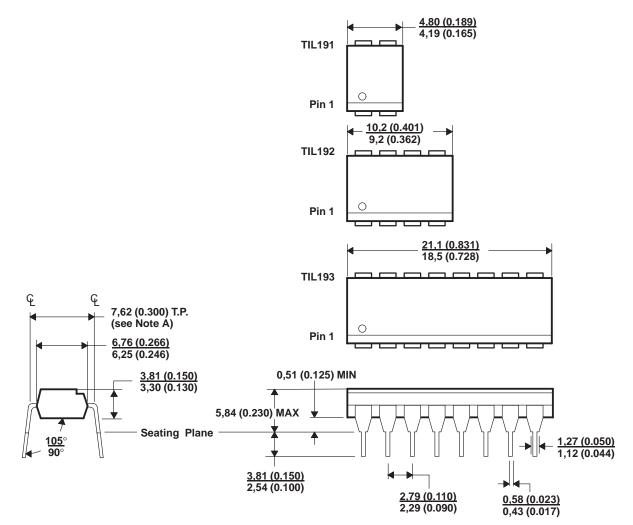






TIL191, TIL192, TIL193, TIL191A, TIL192A, TIL193A TIL191B, TIL192B, TIL193B OPTOCOUPLERS SOES026B – APRIL 1989 – REVISED APRIL 1998

### **MECHANICAL INFORMATION**



NOTES: A. Each pin centerline is located within 0,25 (0.010) of its true longitudinal position. B. All linear dimensions are given in millimeters and parenthetically given in inches.

**Figure 8. Mechanical Information** 



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